Low Power Bipolar Transistors

BC177 / BC177B Series

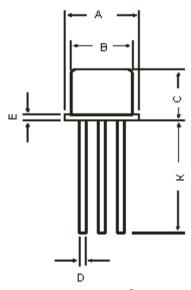




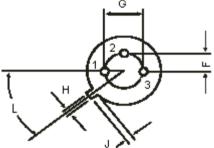
Feature:

• PNP silicon planar epitaxial transistors

TO-18 Metal Can Package



Dimensions	Minimum	Maximum	
А	5.24	5.84	
В	4.52	4.97	
С	4.31	5.33	
D	0.4	0.53	
E	-	0.76	
F	-	1.27	
G	-	2.97	
Н	0.91	1.17	
J	0.71	1.21	
K	12.7	-	
L	45°	45°	



Dimensions : Millimetres



Pin Configuration:

- 1. Emitter
- 2. Base
- 3. Collector



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Absolute Maximum Ratings

Description	Symbol	BC177	Unit	
Collector-Emitter Voltage	V _{CEO}	45		
Collector-Emitter voltage	V _{CES}	50	V	
Collector-Base Voltage	V _{CBO}	V		
Emitter-Base Voltage	V _{EBO}	5		
Collector Current Continuous	I _C	0.2	А	
Power Dissipation at T _a = 25°C Derate Above 25°C		0.6 2.28	W	
Power Dissipation at T _C = 25°C Derate Above 25°C	P _D	1 6.67	mW / °C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +200	°C	
Thermal Resistance				
Junction to Case	R _{th (j-c)}	175	°C / W	

Electrical Characteristics (T_a = 25°C unless otherwise specified)

Description	Symbol	Symbol Test Condition		Typical	Maximum	Unit	
Collector-Cut Off Current	I _{CES}	$V_{CE} = 20 \text{ V, } I_{E} = 0$ $T_{amb} = 125^{\circ}\text{C}$ $V_{CE} = 20 \text{ V, } I_{E} = 0$	-	-	100 4	nΑ μΑ	
Collector-Base Voltage	V _{CBO}	I _E = 10 μA, I _E = 0	50	-	-	V	
Collector-Emitter Voltage	V _{CEO}	I _C = 2 mA, I _B = 0	45	-	-	V	
Emitter-Base Voltage	V_{EBO}	I _E = 10 μA, IC = 0	5	-	-	٧	
DC Current	h _{FE}	I _C = 2 mA, V _{CE} = 5 V BC177 B Group	120 180	-	460 460	-	
Collector Emitter Saturation Voltage	V _{CE (sat)}	I _C = 10 mA, I _B = 0.5 mA	-	-	0.2 0.6		
Base Emitter Saturation Voltage	V _{BE (sat)}	I _C = 100 mA, I _B = 5 mA	-	- 0.9	0.8	V	
Base Emitter on Voltage	V _{BE (on)}	I _C = 2 mA, V _{CE} = 5 V	0.6	-	0.75		



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Electrical Characteristics (T_a = 25°C unless otherwise specified)

Description	Symbol	Test Condition	Minimum	Maximum	Unit
Collector Knee Voltage	V _{CE (K)}	I_C = 10 mA, I_B = The Value for Which I_C = 11 mA at V_{CE} = 1 V	-	0.6	V
Transition Frequency	f _t	V _{CE} = 5 V, I _C = 10 mA f = 50 MHz	200	-	MHz
Noise Figure	NF	$V_{CE} = 5 \text{ V, } I_{C} = 0.2 \text{ mA}$ $R_{g} = 2 \text{ k}\Omega$ $F = 1 \text{ KHz, } B = 200 \text{ Hz}$	-	10	dB
Output Capacitance	C _{obo}	V _{CB} = 10 V, f = 1 MHz	-	4	pF
Small Signal Current Gain	h _{fe}	All $f = 1$ KHz $I_C = 2$ mA, $V_{CE} = 5$ V BC177 B Group	125 240	500 500	-
Input Impedance	h _{ie}	$I_C = 2 \text{ mA}, V_{CE} = 5 \text{ V}$ B Group	3.2	8.5	ΚΩ
Output Admittance	h _{oe}	I _C = 2 mA, V _{CE} = 5 V B Group	-	60	umhos

Specification Table

V _{CEO}	V _{CBO} Maximum (V)	I _C (V)	h _{FE} Minimum at I _C = 2 mA	f _T Minimum (V)	P _{tot} (mW)	Туре	Package	Part Number
45	45 50	0.2	120	200	600	PNP	TO-18	BC177
45	30	50 0.2	180					BC177B

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